

<b>Notice of References Cited</b>	Application/Control No. 10/001,785		Applicant(s)/Patent Under Reexamination YAMAZAKI ET AL.	
	Examiner Craig A. Thompson		Art Unit 2813	Page 1 of 1

**U.S. PATENT DOCUMENTS**

*		Document Number Country Code-Number-Kind Code	Date MM-YYYY	Name	Classification
*	A	US-6,162,667	12-2000	Funai et al.	438/166
	B	US-			
	C	US-			
	D	US-			
	E	US-			
	F	US-			
	G	US-			
	H	US-			
	I	US-			
	J	US-			
	K	US-			
	L	US-			
	M	US-			

**FOREIGN PATENT DOCUMENTS**

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	N					
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**NON-PATENT DOCUMENTS**

*		Include as applicable: Author, Title Date, Publisher, Edition or Volume, Pertinent Pages)
	U	Radnoczi, G. et al. "Al induced crystallization of a-Si." J. Appl. Phys. 1 May 1991, pages 6394-6399
	V	Crowder et al. "Low Temperature Single Crystal Si TFT's Fabricated on Si Films processed via Sequential Lateral Solidification" IEEE Electron Device Letters, Vol 19, No. 8 August 1998, pages 306-308
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\*A copy of this reference is not being furnished with this Office action. (See MPEP § 707.05(a).)  
Dates in MM-YYYY format are publication dates. Classifications may be US or foreign.